

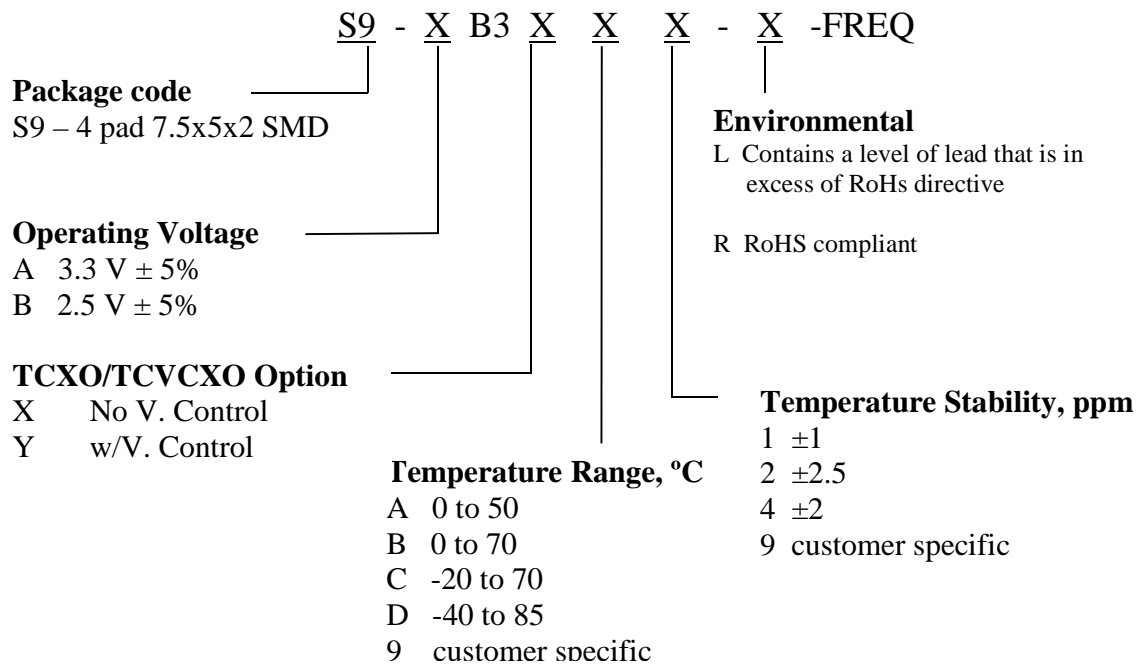
Rev. J

HCMOS TCXO/TCVCXO S9-XB3XXX-X Series

Description

The **S9-XB3XXX Series** of quartz crystal oscillators provide excellent temperature stability with HCMOS output and very low phase noise. The device is packaged in a miniature, low profile leadless FR4 based package with gold plated pads, which enhances compatibility with PCB material. COTS/Dual use.

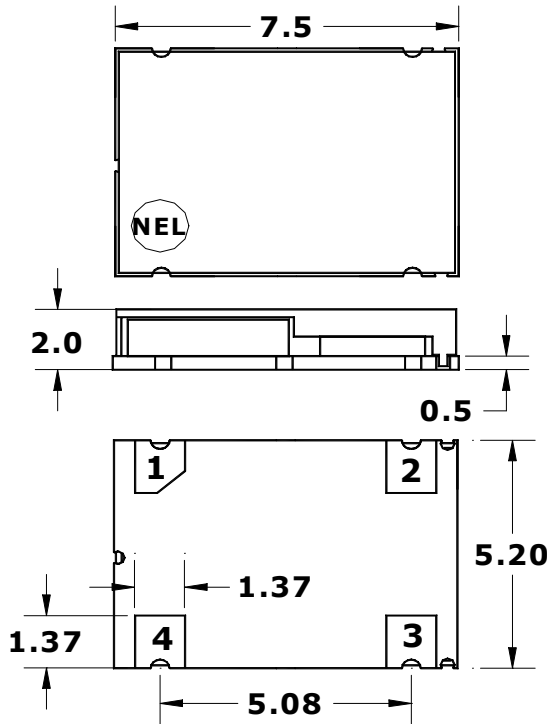
Creating a Part Number



Rev. J

**HCMOS TCXO/TCVCXO
S9-XB3XXX-X Series**

Drawing Specification



Pin Connections:

- 1 – N/C or Vc
- 2 – GND
- 3 – OUT
- 4 – Vcc

Dimensions are typical in mm

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Operating Temperature Range	To	-40 to +85	°C
Storage Temperature Range	Tst	-50 to +90	°C
Supply Voltage	Vcc	-0.5 to 4.5	V
Voltage Control	Vc	0 to Vcc	V



**FREQUENCY
CONTROLS, INC.**

357 Beloit Street, Burlington, WI 53105 U.S.A. Phone 262/763-3591 FAX 2626262/763-2881

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Electrical Parameters (2)

Parameter		Symb	Conditions, Note	MIN	TYP	MAX	Unit
Nominal Frequency		Fo		10.0		120	MHz
Supply Voltage		Vcc	Code A Code B	3.135 2.375	3.3 2.5	3.465 2.625	V
Supply current		Icc	Frequency and Vcc dependent, values for 50 MHz		20	25	mA
Output Logic Type					CMOS		
Load					15 pF/10 KOhm		Ohm
Output Levels		Voh Vol	overall	0.9Vcc		0.1 Vcc	V
Duty Cycle (Symmetry)			At 50% Vcc	45/55	50/50	55/45	%
Rise/Fall Time		Tr/Tf	0.2Vcc to 0.8 Vcc; F< 70 MHz 70 MHz<F< 120 MHz		3 2	5 3	ns
Jitter	Integrated	J	Integrated from Phase Noise, 12 KHz to 20 MHz , RMS		0.2		ps
	Wavecrest characterized		Random period,	At 50 MHz	2.5		ps
			Total, pk-to-pk	At 50 MHz	50		ps
			Deterministic	F>40MHz At 50 MHz	0.0012 0.0025		UI
Sub-harmonics							
Phase Noise ⁽¹⁾		£(Δf)	50 MHz	@ 10 Hz @ 100 Hz @ 1 KHz @ 10KHz @ 100KHz @ >1MHz	-75 -105 -125 -138 -138 -140	-135	dBc/Hz
Frequency stability		ΔF/F	Over Temp -30 to 80 C See chart Aging, 1 st year Aging 10 years Load Vcc Reflow Calibration as shipped		2.5	1 3.5 0.1 0.1/V 2 1	ppm
Pullability (Vc option)			0.3V to 3.0V	5			ppm

Footnote: 1) If phase noise data at a particular frequency is needed, contact factory.

2) All parameters, unless otherwise specified, are at nominal conditions, ie: T=25°C, Nominal Vcc & Nominal Load.



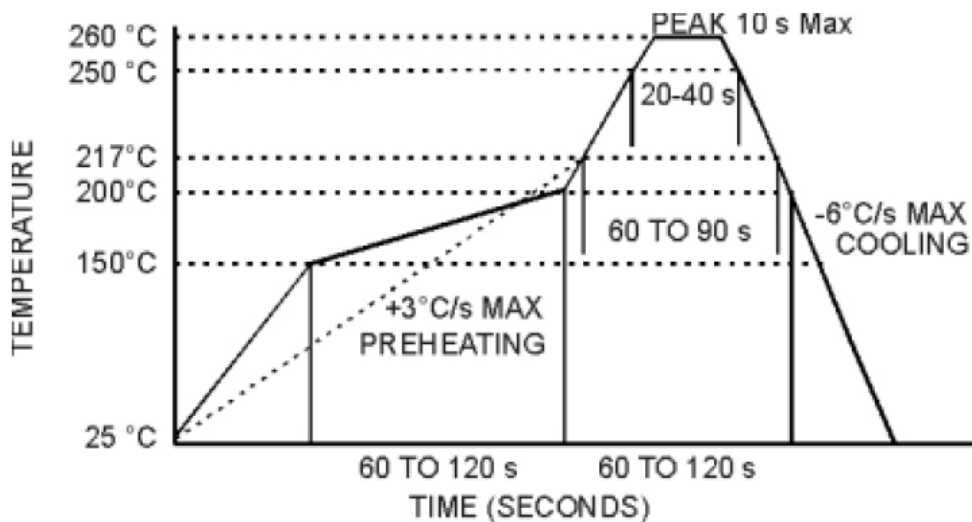
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Environmental and Mechanical Characteristics

Operating temp. range	see part # table
Mechanical Shock	Per MIL-STD-202, Method 213, Cond. A
Thermal Shock	Per MIL-STD-883, Method 1011, Cond. A
Vibration	Per MIL-STD-883, Method 2007, Cond. A
Hermetic Seal	Leak rate less than 1×10^{-8} atm.cc/s of helium (Crystal only)
Soldering conditions	See MAX reflow profile below; The device may be reflowed once. Reflowing upside down is not allowed. NO CLEAN assembly is recommended.

MAX Reflow Profile



The device may be reflowed once. Reflowing upside down is not allowed. NO CLEAN assembly is recommended.

